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Information Disclosure Statement by Applicant

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APPLICANT
AOKI

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U.S. Patent Documents

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Examiner Initial	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE

Foreign Patent Documents

Examiner Initial	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLASS	TRANSLATION	
					YES	NO
GJM	8-330680	5/22/96	Japan		Abstract	X
GJM	11-87831	9/2/97	Japan		Abstract	X
GJM	2000-68610	3/27/96	Japan		Abstract	X
GJM	10-11781	6/19/96	Japan		Abstract	X
GJM	6-302003	4/12/93	Japan		Abstract	X
GJM	2000-138411	10/29/98	Japan		Abstract	X

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

<i>GJM</i>	F. Issiki, S. Fukatsu, Y. Shiraki, "Efficient Luminescence from AIP/GaP Neighboring Confinement Structure with AlGaP Barrier Layers", 1995 American Institute of Physics, Appl. Phys. Lett., 67 (8), 21 August 1995, pp. 1048-1050.
<i>GJM</i>	N. Usami, F. Issiki, K. Nayak, Y. Shiraki and S. Fukatsu, "Enhancement of Radiative Recombination in Si-based Quantum Wells with Neighboring Confinement Structure", 1995 American Institute of Physics, Appl. Phys. Lett., 67 (4), 24 July 1995, pp. 524-526.

EXAMINER

DATE CONSIDERED

9 - 03

EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant



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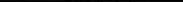
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BM S. Rennon, K. Avary, F. Klopf, A. Wolf, M. Emmerling, J.-P. Reithmaier, A. Forchel, "Edge-emitting microlasers with a single quantum dot active layer", 17th Semiconductor Laser International Conference, technical digest paper THA5, pp. 139-140 *no date available*

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